

INVENTOR INFORMATION

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APPLICATION INFORMATION

Title Line One:: NONVOLATILE MEMORY, SEMICONDUCTOR DEVICE
Title Line Two:: AND METHOD OF MANUFACTURING THE SAME
Total Drawing Sheets:: 13
Formal Drawings?: Yes
Application Type:: Utility
Docket Number:: 740756-2255
Secrecy Order in Parent Appl.?: No

REPRESENTATIVE INFORMATION

Registration Number One:: 35483
Registration Number Two:: 38285
Registration Number Three:: 45285
Registration Number Four:: 20932
Registration Number Five:: 26477

PRIOR FOREIGN APPLICATIONS

Foreign Application One:: 2000-023656

Filing Date:: 02-01-2000

Country:: Japan

Priority Claimed:: Yes

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